

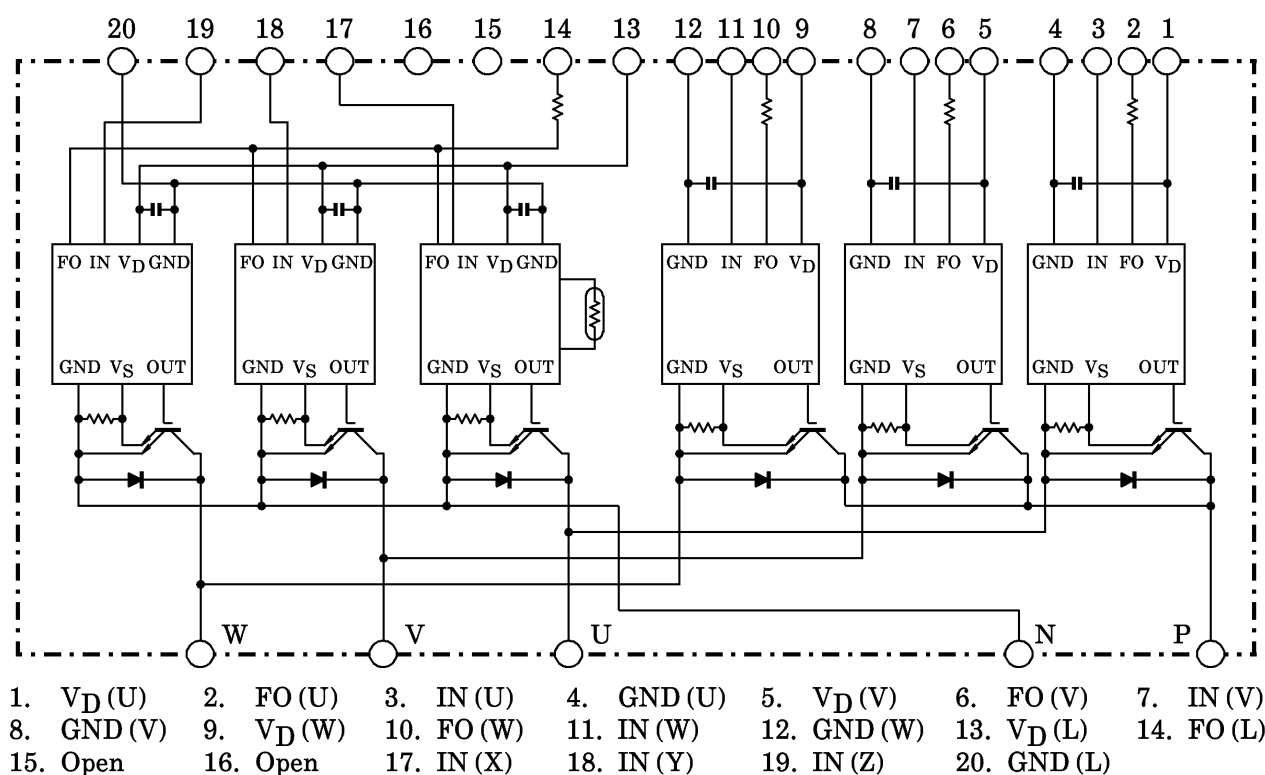
MIG150Q6CMA0X (1200V / 150A 6in1)

HIGH POWER SWITCHING APPLICATION

MOTOR CONTROL APPLICATION

- Integrates Inverter Power Circuits & Control Circuits (IGBT drive units, Protection units for Short-Current, Over-Current, Under-Voltage & Over Temperature) in One Package.
- The Electrode are Isolated from Case.
- $V_{CE(sat)} = 2.4 \text{ V (Typ.)}$

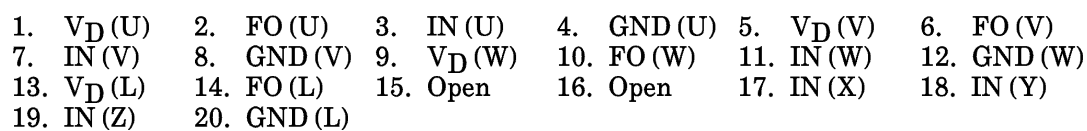
EQUIVALENT CIRCUIT



961001EAA1

- TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.

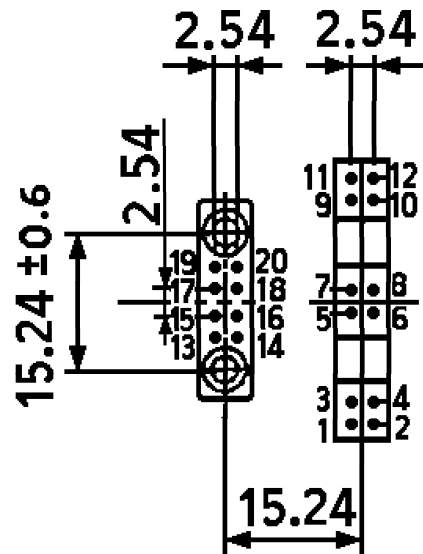
Unit : mm



2000-03-06 2/8

SIGNAL TERMINAL LAYOUT

Unit : mm



- | | | | | | |
|------------------------|-------------|-----------------------|------------|-----------------------|-------------|
| 1. V _D (U) | 2. FO (U) | 3. IN (U) | 4. GND (U) | 5. V _D (V) | 6. FO (V) |
| 7. IN (V) | 8. GND (V) | 9. V _D (W) | 10. FO (W) | 11. IN (W) | 12. GND (W) |
| 13. V _D (L) | 14. FO (L) | 15. Open | 16. Open | 17. IN (X) | 18. IN (Y) |
| 19. IN (Z) | 20. GND (L) | | | | |

MAXIMUM RATINGS

STAGE	CHARACTERISTIC	CONDITION	SYMBOL	RATING	UNIT
Inverter	Supply Voltage	P-N Power Terminal	V_{CC}	900	V
	Collector-Emitter Voltage	—	V_{CES}	1200	V
	Collector Current	$T_c = 25^\circ\text{C}$, DC	I_C	150	A
	Forward Current	$T_c = 25^\circ\text{C}$, DC	I_F	150	A
	Collector Power Dissipation	$T_c = 25^\circ\text{C}$	P_C	1000	W
	Junction Temperature	—	T_j	150	$^\circ\text{C}$
Control	Control Supply Voltage	V_D -GND Terminal	V_D	20	V
	Input Voltage	IN-GND Terminal	V_{IN}	20	V
	Fault Output Voltage	FO-GND Terminal	V_{FO}	20	V
	Fault Output Current	FO Sink Current	I_{FO}	14	mA
Module	Operating Temperature	—	T_c	$-20 \sim +100$	$^\circ\text{C}$
	Storage Temperature Range	—	T_{stg}	$-40 \sim +125$	$^\circ\text{C}$
	Isolation Voltage	AC 1 minute	V_{ISO}	2500	V
	Screw Torque	M5	—	3	Nm

ELECTRICAL CHARACTERISTICS

a. Inverter Stage ($T_j = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Collector Cut-Off Current	I_{CEX}	$V_{CE} = 1200\text{ V}$	$T_j = 25^\circ\text{C}$	—	—	1	mA
			$T_j = 125^\circ\text{C}$	—	—	10	
Collector-Emitter Saturation Voltage	$V_{CE}(\text{sat})$	$V_D = 15\text{ V}$, $I_C = 150\text{ A}$, $V_{IN} = 15\text{ V} \rightarrow 0\text{ V}$	$T_j = 25^\circ\text{C}$	—	2.4	2.8	V
			$T_j = 125^\circ\text{C}$	—	—	3.2	
Forward Voltage	V_F	$I_F = 150\text{ A}$		—	2.5	3.1	V
Switching Time	t_{on}	$V_{CC} = 600\text{ V}$, $I_C = 150\text{ A}$ $V_D = 15\text{ V}$, $V_{IN} = 15\text{ V} \leftrightarrow 0\text{ V}$ Inductive Load (Note 1)		—	1.0	2.0	μs
	$t_c(\text{on})$			—	0.6	1.2	
	t_{rr}			—	0.3	0.6	
	t_{off}			—	2.0	3.0	
	$t_c(\text{off})$			—	0.3	0.7	

b. Control Stage ($T_j = 25^\circ\text{C}$)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Control Circuit Current	High Side	$I_D(H)$	$V_D = 15\text{ V}$	—	8	12	mA
	Low Side	$I_D(L)$		—	34	50	
Input On Signal Voltage		$V_{IN(on)}$	$V_D = 15\text{ V}$	1.4	1.6	1.8	V
Input Off Signal Voltage		$V_{IN(off)}$		2.2	2.5	2.8	
Fault Output Current	Protection	$I_{FO(on)}$	$V_D = 15\text{ V}$	—	10	12	mA
	Normal	$I_{FO(off)}$		—	—	0.1	
Over Current Protection Trip Level	Inverter	OC	$V_D = 15\text{ V}, T_j \leq 125^\circ\text{C}$	240	—	—	A
Short Circuit Protection Trip Level	Inverter	SC	$V_D = 15\text{ V}, T_j \leq 125^\circ\text{C}$	300	—	—	A
Over Current Cut-Off Time		$t_{off(OC)}$	$V_D = 15\text{ V}$	—	5	—	μs
Over Temperature Protection	Trip Level	OT	Case Temperature	110	118	125	$^\circ\text{C}$
	Reset Level	OTr		—	98	—	
Control Supply Under Voltage Protection	Trip Level	UV	—	11.0	12.0	12.5	V
	Reset Level	UVr		12.0	12.5	13.0	
Fault Output Pulse Width		t_{FO}	$V_D = 15\text{ V}$	1	2	3	ms

c. Thermal Resistance ($T_c = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Junction to Case Thermal Resistance	$R_{th(j-c)}$	IGBT	—	—	0.125	$^\circ\text{C} / \text{W}$
		FRD	—	—	0.357	

(Note 1) : Switching time test circuit & timing chart

